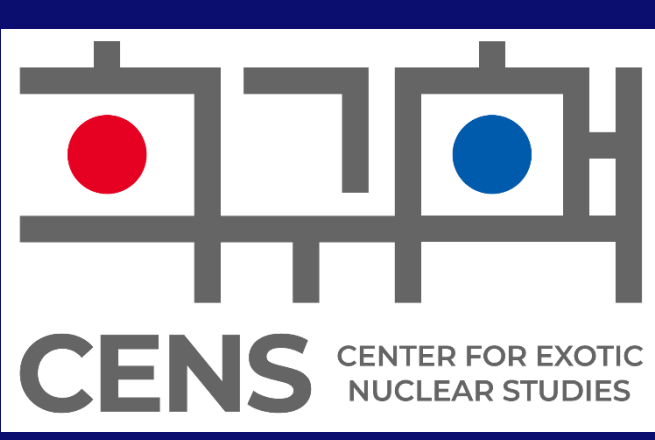


Study on the application of SiPM to γ ray and charged particle measurement using scintillation crystals

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Characteristics of SiPM

• Silicon Photo Multiplier

- High density pixel array ($\sim 10^2$ pixel/mm²)
- Single-photon avalanche photodiode (Geiger mode)
- Fast rise time (\sim ns)
- Compact size (< 1 cm² per SiPM)
- Highly resistant to magnetic field

Advantages over PMT

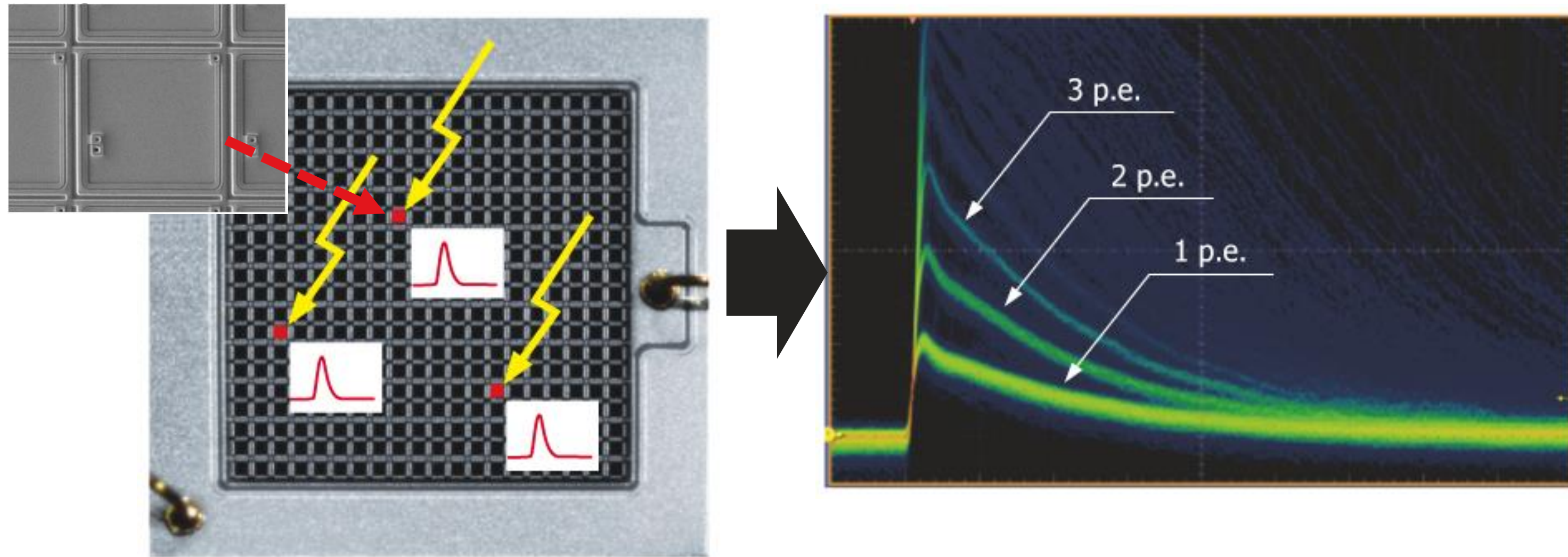


Figure 1. A schematic drawing for the structure and output signals of SiPM, taken from Ref. [1], [2].

Test Assembly

• SiPM

- S13360-6050PE MPPC from HAMAMATSU
- 6×6 mm², 14400 pixels/MPPC, 50 μ m pixel-pitch
- $\lambda_{\text{response}}$: 320 ~ 900 nm (λ_{peak} : 450 nm), $V_{\text{operation}}$: 56 V (± 5)

• Scintillators

- GAGG:Ce crystal ($\text{Gd}_3\text{Al}_2\text{Ga}_3\text{O}_{12}:\text{Ce}$)
- $40 \times 40 \times 5$, $40 \times 40 \times 3$ mm³, λ_{peak} : 520 nm, τ_{decay} : 0.2 μ s, ~ 50 k photons/MeV

• DAQ with CAEN V1730SD digitizer

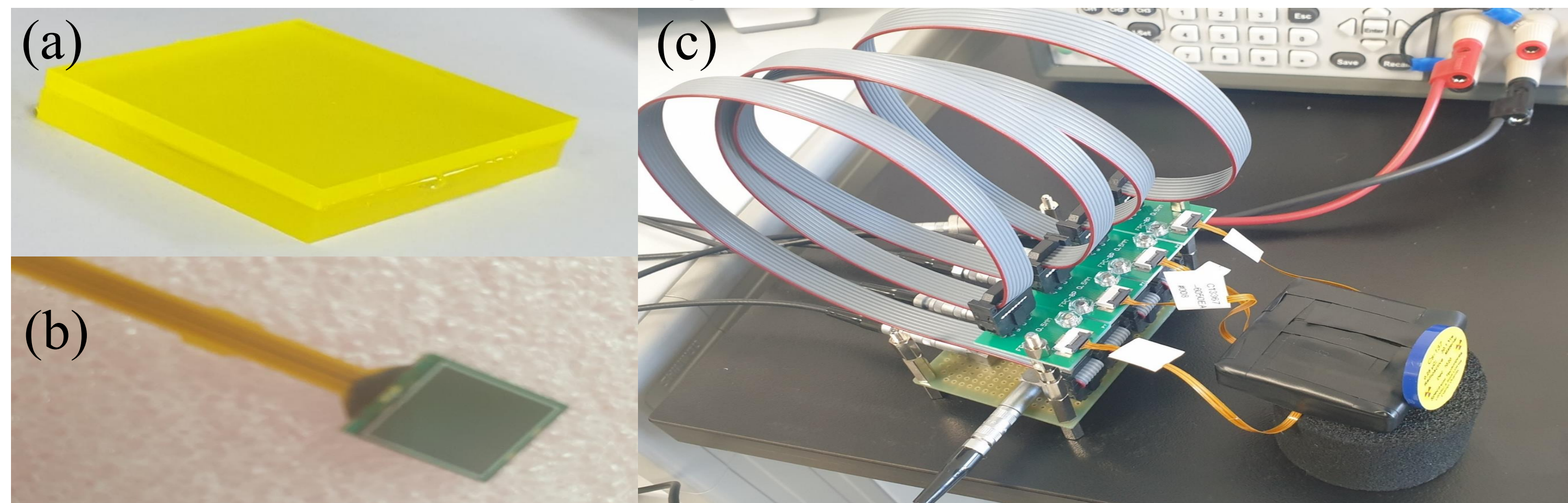


Figure 2. Two stacked GAGG:Ce crystals (a), SiPM connected with FPC cable (b) and quadruple-SiPM GAGG:Ce assembly (c)

Miscellaneous Characteristics

• Position dependence

- Possible application for a coarse position estimation of the source.

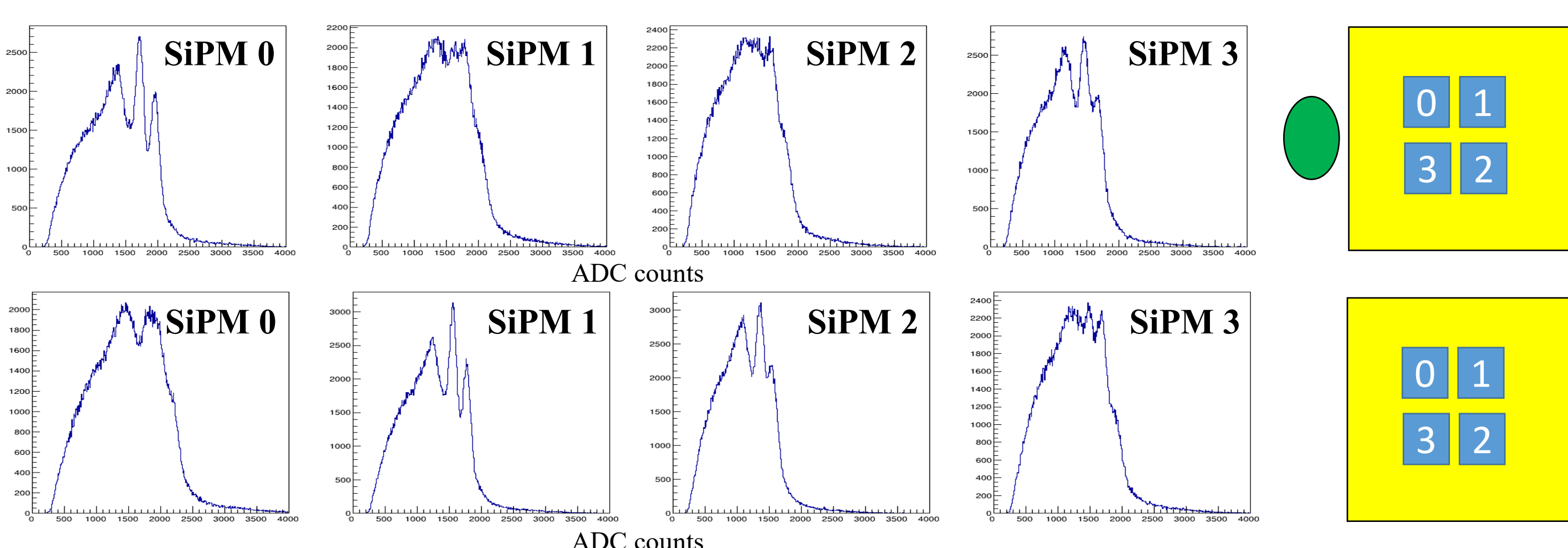


Figure 3. ADC counts distribution for different geometries. The corresponding geometry of ⁶⁰Co source (green), GAGG:Ce (yellow) and SiPM (blue) are drawn on the right-side.

• Geometric mean for comfortable multi-SiPM signal processing

- Using $A_{\text{total}} = (A_0 \times A_1 \times A_2 \dots A_n)^{1/n}$ instead of $A_{\text{total}} = (A_0 + A_1 + A_2 \dots A_n)/N$
- Comparable energy resolutions to the arithmetic mean with gain matching
- Advantage: applicable before the gain matching for each SiPM

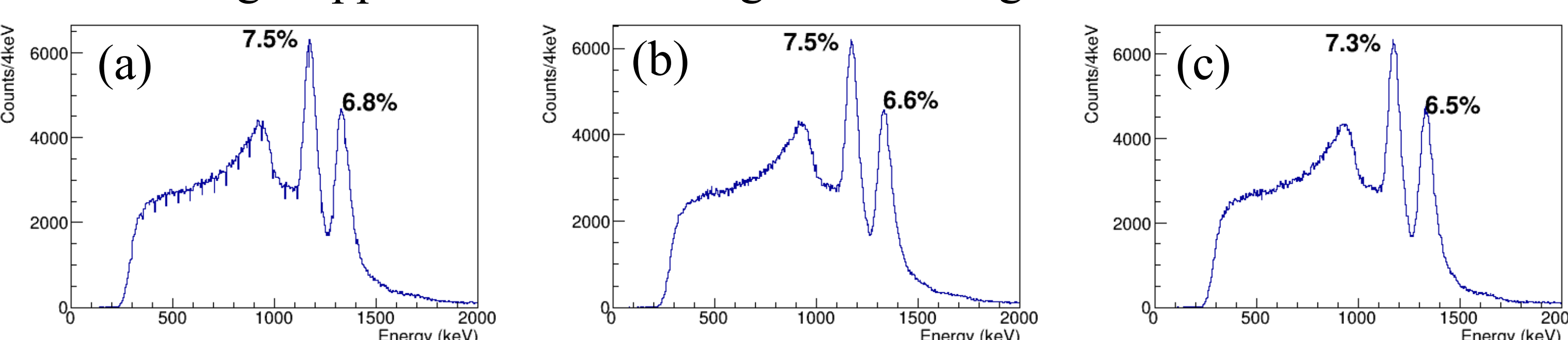


Figure 4. The energy resolutions with ⁶⁰Co source. The arithmetic mean of raw ADC is (a) and gain-matched ADC with ¹³⁷Cs data is (b) and the geometric mean of raw ADC is (c).

Energy Resolution

- Radiation sources: ¹³⁷Cs ($E_\gamma = 662$ keV), ⁶⁰Co ($E_\gamma = 1.17, 1.33$ MeV)

- E resolution was better with higher bias and merged quadruple SiPM

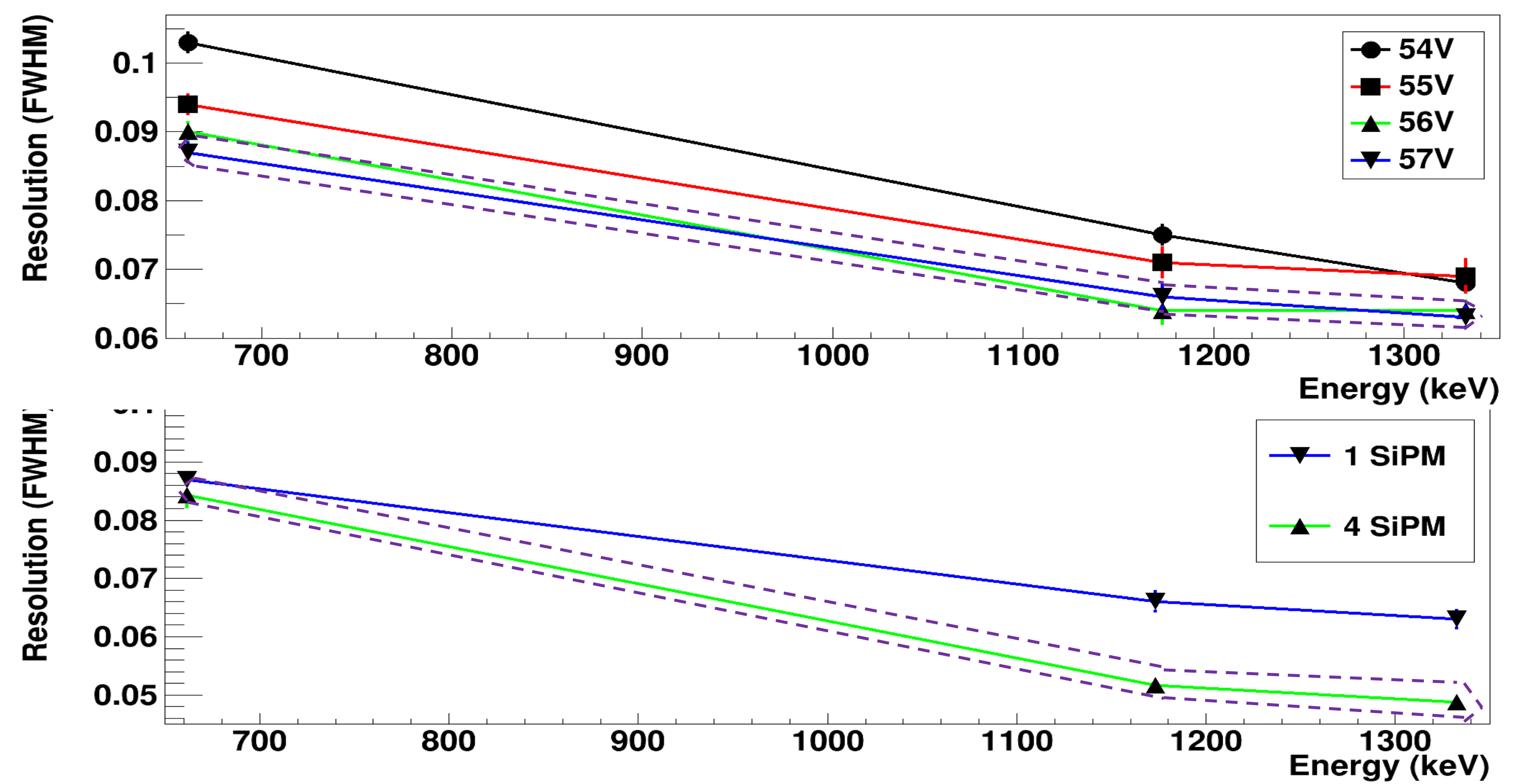


Figure 5. The effects of bias voltage on energy resolution for single SiPM assembly (upper) and resolution comparison with quadruple SiPM assembly (lower). Quadruple SiPM with 57 V bias showed best energy resolution (inside dashed line).

Applications Plans

• CsI-SiPM calorimeter for active target TPC

- Reaction vertex and type identification
- CsI-SiPM for calorimeter of γ , p and α
- Micromegas and DSSD for charged particle tracking and PID
- γ rays coincident with charged particles
- TexAT_v2, ATOM-X

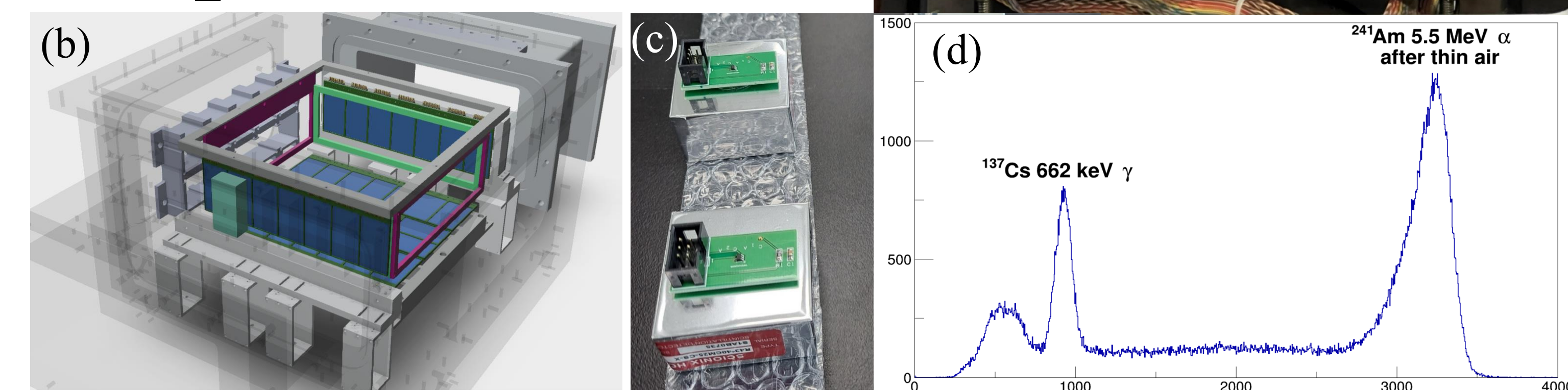


Figure 6. (a) Schematic drawing for TexAT and (b) the picture for TexAT assembly. CsI-SiPM were placed behind the Si detectors. The CsI-SiPM assemblies are as in (c). Test result for ¹³⁷Cs and ²⁴¹Am source is in (d). The FWHM for ¹³⁷Cs γ peak was 11%. The broad α peak is due to partly removed reflective mylar foil for α particle transmission.

• Segmented plastic scintillator + SiPM array (under developing)

- High time resolution achievable (< 100 ps) [3]
- Segmentation for position determination and multiplicity identification

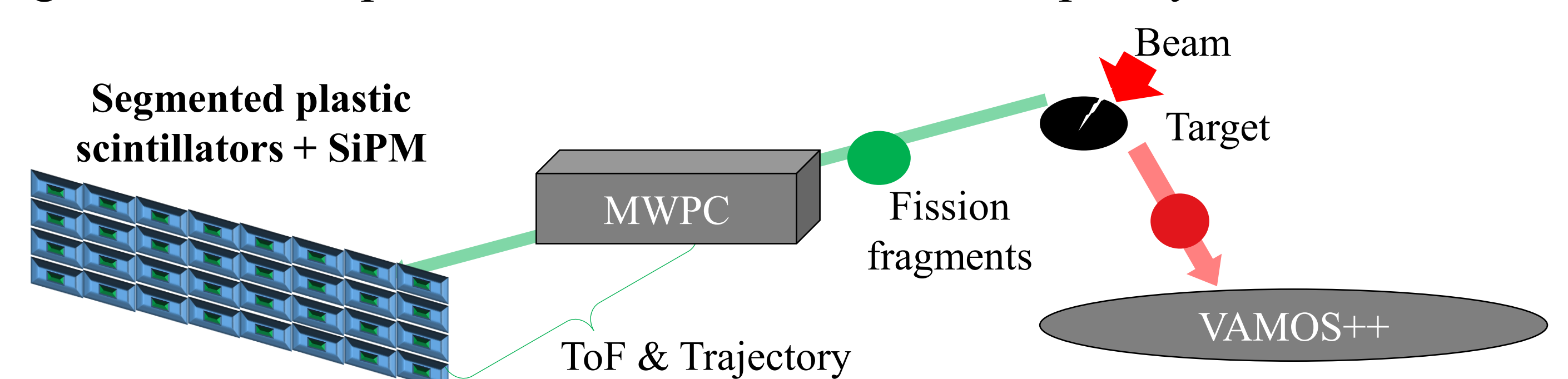


Figure 7. A schematic drawing for possible segmented ToF detector for GANIL VAMOS++ spectrometer

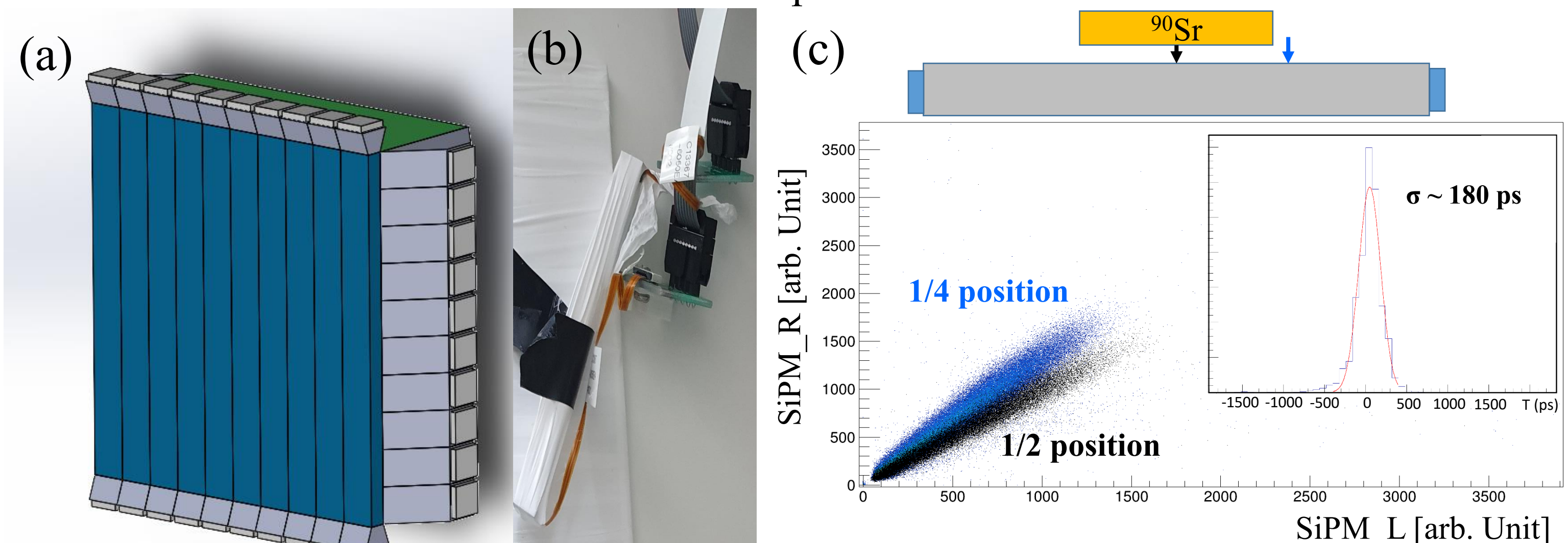


Figure 8. (a) Schematic view and (b) test assembly of SiPM-plastic scintillator (BC420) array for β decay detection in an approved ANL experiment. (c) A simple drawing for the bench test and its results that show position dependency of signals and time resolution.

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- [2] Hamamatsu Photonics K. K., https://www.hamamatsu.com/jp/en/product/optical-sensors/mppc/what_is_mppc/index.html.
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